

1113.40340X00 filed 07/20/01

U.S. APPLICATION NO. (If known, see 37 CFR 1.5)

097889788

TRANSMITTAL LETTER TO THE UNITED STATES
DESIGNATED/ELECTED OFFICE (DO/EO/US)
CONCERNING A FILING UNDER 35 U.S.C. 371

INTERNATIONAL APPLICATION NO.	INTERNATIONAL FILING DATE	PRIORITY DATE CLAIMED
PCT/JP99/00244	22 January 1999 (22.01.99)	
TITLE OF INVENTION LIQUID CRYSTAL DISPLAY DEVICE		
APPLICANT(S) FOR DO/EO/US SETSUO KOBAYASHI and KAZUHIKO YANAGAWA		

Applicant herewith submits to the United States Designated/Elected Office (DO/EO/US) the following items and other information:

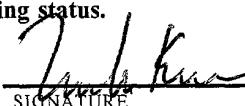
1. This is a **FIRST** submission of items concerning a filing under 35 U.S.C. 371.
2. This is a **SECOND** or **SUBSEQUENT** submission of items concerning a filing under 35 U.S.C. 371.
3. This is an express request to begin national examination procedures (35 U.S.C. 371(f)). The submission must include items (5), (6), (9) and (21) indicated below.
4. The US has been elected by the expiration of 19 months from the priority date (Article 31).
5. A copy of the International Application as filed (35 U.S.C. 371(c)(2))
 - a. is attached hereto (required only if not communicated by the International Bureau).
 - b. has been communicated by the International Bureau.
 - c. is not required, as the application was filed in the United States Receiving Office (RO/US).
6. An English language translation of the International Application as filed (35 U.S.C. 371(c)(2))
 - a. is attached hereto.
 - b. has been previously submitted under 35 U.S.C. 154(d)(4).
7. Amendments to the claims of the International Application under PCT Article 19 (35 U.S.C. 371(c)(3))
 - a. are attached hereto (required only if not communicated by the International Bureau).
 - b. have been communicated by the International Bureau.
 - c. have not been made; however, the time limit for making such amendments has NOT expired.
 - d. have not been made and will not be made.
8. An English language translation of the amendments to the claims under PCT Article 19 (35 U.S.C. 371(c)(3)).
9. An oath or declaration of the inventor(s) (35 U.S.C. 371(c)(4)).
10. An English language translation of the annexes of the International Preliminary Examination Report under PCT Article 36 (35 U.S.C. 371(c)(5)).

Items 11 to 20 below concern document(s) or information included:

11. An Information Disclosure Statement under 37 CFR 1.97 and 1.98.
12. An assignment document for recording. A separate cover sheet in compliance with 37 CFR 3.28 and 3.31 is included.
13. A **FIRST** preliminary amendment.
14. A **SECOND** or **SUBSEQUENT** preliminary amendment.
15. A substitute specification.
16. A change of power of attorney and/or address letter.
17. A computer-readable form of the sequence listing in accordance with PCT Rule 13ter.2 and 35 U.S.C. 1.821 - 1.825.
18. A second copy of the published international application under 35 U.S.C. 154(d)(4).
19. A second copy of the English language translation of the international application under 35 U.S.C. 154(d)(4).
20. Other items or information:

Credit Card Payment Form

Figs. 1-6

US APPLICATION NO (If known, see 37 CFR 1.492(e)) 097889788	INTERNATIONAL APPLICATION NO PCT/JP99/00244	ATTORNEY'S DOCKET NUMBER 1113.40340X00		
21. <input checked="" type="checkbox"/> The following fees are submitted: BASIC NATIONAL FEE (37 CFR 1.492 (a) (1) - (5)): Neither international preliminary examination fee (37 CFR 1.482) nor international search fee (37 CFR 1.445(a)(2)) paid to USPTO and International Search Report not prepared by the EPO or JPO \$1000.00 International preliminary examination fee (37 CFR 1.482) not paid to USPTO but International Search Report prepared by the EPO or JPO \$860.00 International preliminary examination fee (37 CFR 1.482) not paid to USPTO but international search fee (37 CFR 1.445(a)(2)) paid to USPTO \$710.00 International preliminary examination fee (37 CFR 1.482) paid to USPTO but all claims did not satisfy provisions of PCT Article 33(1)-(4) \$690.00 International preliminary examination fee (37 CFR 1.482) paid to USPTO and all claims satisfied provisions of PCT Article 33(1)-(4) \$100.00		CALCULATIONS PTO USE ONLY		
ENTER APPROPRIATE BASIC FEE AMOUNT =		\$ 860.00		
Surcharge of \$130.00 for furnishing the oath or declaration later than <input type="checkbox"/> 20 <input type="checkbox"/> 30 months from the earliest claimed priority date (37 CFR 1.492(e)).		\$ 0.00		
CLAIMS	NUMBER FILED	NUMBER EXTRA	RATE	\$
Total claims	7 -20 =	0	x \$18.00	\$ 0.00
Independent claims	2 -3 =	0	x \$80.00	\$ 0.00
MULTIPLE DEPENDENT CLAIM(S) (if applicable)			+ \$270.00	\$ 270.00
TOTAL OF ABOVE CALCULATIONS =		\$ 1,130.00		
<input type="checkbox"/> Applicant claims small entity status. See 37 CFR 1.27. The fees indicated above are reduced by 1/2.		+ \$ 0.00		
SUBTOTAL =		\$ 1,130.00		
Processing fee of \$130.00 for furnishing the English translation later than <input type="checkbox"/> 20 <input type="checkbox"/> 30 months from the earliest claimed priority date (37 CFR 1.492(f)).		\$ 0.00		
TOTAL NATIONAL FEE =		\$ 1,130.00		
Fee for recording the enclosed assignment (37 CFR 1.21(h)). The assignment must be accompanied by an appropriate cover sheet (37 CFR 3.28, 3.31). \$40.00 per property		+ \$ 0.00		
TOTAL FEES ENCLOSED =		\$ 1,130.00		
		Amount to be refunded:	\$	
		charged:	\$	
<p>a. <input type="checkbox"/> A check in the amount of \$ _____ to cover the above fees is enclosed.</p> <p>b. <input type="checkbox"/> Please charge my Deposit Account No. _____ in the amount of \$ _____ to cover the above fees. A duplicate copy of this sheet is enclosed.</p> <p>c. <input checked="" type="checkbox"/> The Commissioner is hereby authorized to charge any additional fees which may be required, or credit any overpayment to Deposit Account No. <u>01-2135</u>. A duplicate copy of this sheet is enclosed.</p> <p>d. <input checked="" type="checkbox"/> Fees are to be charged to a credit card. WARNING: Information on this form may become public. Credit card information should not be included on this form. Provide credit card information and authorization on PTO-2038.</p>				
<p>NOTE: Where an appropriate time limit under 37 CFR 1.494 or 1.495 has not been met, a petition to revive (37 CFR 1.137 (a) or (b)) must be filed and granted to restore the application to pending status.</p>				
<p>SEND ALL CORRESPONDENCE TO:</p> <p>Melvin Kraus Antonelli, Terry, Stout & Kraus, LLP 1300 North Seventeenth Street Suite 1800 Arlington, VA 22209</p>				
<p> SIGNATURE</p> <p><u>Melvin Kraus</u> NAME</p> <p><u>22,466</u> REGISTRATION NUMBER</p>				

DESCRIPTION

LIQUID CRYSTAL DISPLAY DEVICE

[Technical Field]

The present invention relates to a liquid crystal display device in which an electric field is applied in a direction approximately parallel to flat surfaces of substrates to drive a liquid crystal. It is particularly effective for application to a liquid crystal display device in which a residual image caused by pure AC driving is reduced, excellent display characteristics are provided and a productivity is excellent.

[Background of the Invention]

In an ordinary liquid crystal display device, a longitudinal electric field system typified by a twisted nematic display system in which an electrode driving a liquid crystal layer held between a pair of substrates is constructed of a transparent electrode formed opposite to each of the pair of substrates and an electric field provided in a direction approximately vertical to the surfaces of the substrates is applied to drive a liquid crystal was employed.

On the other hand, a lateral electric field system in which an electric field applied to a liquid crystal is provided in a direction approximately parallel to surfaces of substrates was developed. As an example of this system, the use of a pair of comb-like electrodes in which an electrode providing an

electric field approximately in parallel with the surfaces of the electrodes is formed on one of the substrates is disclosed in, for example, Japanese Patent Publication No. 21,907/1988, U. S. Patent Specification No. 4,345,249, European Patent No. 91/10,936, Japanese Patent Laid-Open Nos. 222,397/1994 and 160,878/1994, and the like. It is unnecessary that the electrodes disclosed in these documents are transparent, and opaque metal electrodes having a high conductivity are used.

In the display system in which the direction of the electric field applied to the liquid crystal is a direction approximately parallel to the surfaces of the substrates as disclosed in the above-mentioned documents, a method for reducing display unevenness present from the outset, such as an edge domain has been proposed to date in Japanese Patent Laid-Open No. 159,786/1995. However, a construction or the like which is required for eliminating display unevenness occurring in a stress test such as a high-temperature working test or the like and improving a productivity is not described at all.

Applicant of the present application has found, with respect to the foregoing liquid crystal display device of the lateral electric field system, that usual AC driving is conducted at a high temperature of 55°C or the like to form a residual image (this is referred to as an AC residual image) which leads to a display defect.

For eliminating this display unevenness, Applicant of the application has made assiduous effort, and has consequently confirmed that it is not observed so long as the AC residual image is below a certain percentage. And, it has been found that for coping with the display defect caused by the display unevenness, it is effective to use a specific oriented film and increase an interaction between the oriented film and the liquid crystal molecules.

It has been moreover found that a silane coupling agent in the oriented film which is ordinarily used to improve an adhesion with substrates influences the display unevenness.

The invention aims to provide a liquid crystal display device that enables high-quality image display upon eliminating the display defect caused by the AC residual image.

[Disclosure of the Invention]

The invention is characterized by the construction described in the following (1) to (6).

(1) A liquid crystal display device comprising a pair of substrates and a liquid crystal layer held between the pair of substrates, at least one of the pair of substrates being provided with plural electrodes for applying an electric field to the liquid crystal layer, a protecting film for protecting at least one of the plural electrodes and oriented films formed to cover the protecting film or the electrodes, in which the film thickness of the protecting film is in the range

of from 0.1 μm to 0.7 μm , and

an AC residual image of the oriented films is less than 8 %.

(2) A specific resistance of the liquid crystal layer is $10^{10} \Omega\cdot\text{cm}$ or more.

(3) At least one of the oriented films in (1) or (2) is an organic polymer containing at least one of a polymer and an oligomer in which a weight substance with a long-chain alkyl group applied to an amine component or an acid sentence is at least 5 % and at most 30 % of the total molar amount.

(4) A weight average molecular weight of the polymer and the oligomer in (3) is at least 2,000 and at most 30,000.

(5) The polymer and the oligomer in (3) or (4) contain a long-chain alkylene group of at least one of a main chain type and a terminal type.

(6) The oriented film in (1) to (5) is an organic polymer of a polymer and/or oligomer amic acid imide type, a polymer and/or oligomer amide-imide type, a polymer and/or oligomer imidosiloxane type or a polymer and/or oligomer amide-imide type containing a long-chain alkylene group.

(7) A liquid crystal display device comprising a pair of substrates and a liquid crystal layer held between the pair of substrates,

at least one of the pair of substrates being provided with at least a pair of electrodes for applying an electric

field to the liquid crystal layer,
protecting films for protecting the plural electrodes
and

oriented films formed on the protecting films and the
electrodes, in which

the film thickness of the protecting films is less than
0.5 μm , and

an AC residual image of the oriented films is less than
8 %.

[Brief Description of the Drawings]

Fig. 1 is a schematic sectional view showing a simplified structure of one substrate, which describes a first working example of a liquid crystal display device according to the invention;

Fig. 2 is a schematic plan view showing a construction of various electrodes in a unit pixel, which describes the first working example of the liquid crystal display device according to the invention;

Fig. 3 is an equivalent circuit diagram describing a driving structure of the first working example of the liquid crystal display device according to the invention;

Fig. 4 is a descriptive view of a rubbing angle and an angle of a deflection plate in the liquid crystal display device according to the invention;

Fig. 5 is a block diagram of a measurement system for evaluating change in B-V characteristics; and

Fig. 6 is a sectional view of an overlapped portion of a pixel electrode and a passivation film.

[Best Mode for Carrying Out the Invention]

The invention is described in more detail below by referring to the drawings attached. By the way, in the invention, the scope of claims of the invention is not limited to the following Examples.

(Example 1)

Fig. 1 is a schematic sectional view showing a simplified structure of one substrate, which describes the first working example of the liquid crystal display device according to the invention.

The substrate shown is a substrate on which electrodes are formed in a liquid crystal display device of a lateral electric field system. 1 is a common electrode, 2 a gate insulation film, 3 a pixel electrode, 4 a passivation film (insulation film), 5 an oriented film, 7 a glass substrate constituting a substrate on which electrodes are formed, 11 a thin film transistor, and 12 a picture signal electrode.

Further, Fig. 2 is a schematic plan view showing a construction of various electrodes in a unit pixel, which describes the first working example of the liquid crystal display

device according to the invention. 9 is a scanning signal electrode, and 10 amorphous Si.

The scanning signal electrode 9 and the common electrode 1 are formed on a glass substrate 7 polished, and the surfaces of the scanning signal electrode 9 and the common electrode 1 are coated with an alumina film which is an anode oxide film of aluminum Al.

A gate insulation film 2 made of a silicon nitride SiN film and an amorphous silicon a-Si film 10 are formed to cover the scanning signal electrode 9 and the common electrode 1, and the n-type a-Si film, the pixel electrode 3 and the picture signal electrode 12 are formed on this a-Si film 10.

A laminated electrode using chromium Cr in an undercoat layer and aluminum Al in an upper layer is used as the pixel electrode 3 and the picture signal electrode 12. The film thickness is 0.2 μm in total.

The materials of the scanning signal electrode 9, the common electrode 1, the pixel electrode 3 and the picture signal electrode 12 are not limited to the foregoing materials, and they are not limited so long as they are metallic materials having a low electric resistance. For example, a metal such as chromium, aluminum, copper, niobium or the like, an alloy such as CrMo, AlTiTa or the like, or a laminated structure using aluminum in an undercoat layer and chromium in an upper layer is also available.

The pixel electrode 3 and the picture signal electrode 12 have, as shown in Fig. 2, a structure that both are parallel to the striped common electrode 1 and intersect the scanning signal electrode 9, and a transistor element (thin film transistor TFT) 11 and a metal electrode group are formed on one substrate.

Consequently, an electric field provided between the pixel electrode 3 and the common electrode 1 on one substrate is formed approximately in parallel with the surface of the substrate.

The electrode arrangement is not limited to that shown in Fig. 2. A structure for making the driving direction of the liquid crystal bidirectional in the pixel, for example, a structure that the common electrode 1 and the pixel electrode 3 are in zigzag fashion or a structure that the common electrode 1 and the pixel electrode 3 are not parallel to the picture signal electrode 12 is also available.

The number of pixels is 1,024 (x 3) x 768, and the pixel pitch is 88 μm in a lateral direction (namely, between common electrodes) and 264 μm in a longitudinal direction (namely, between scanning signal electrodes). Further, a substrate (not shown) opposite to the substrate having the transistor element is provided thereon with a striped color filter of R, G and B three colors.

A transparent resin for flattening a surface is laminated

on this color filter. An epoxy resin is used as a material of the transparent resin. Further, a polyimide-based oriented film is coated on the transparent resin.

Fig. 3 is an equivalent circuit diagram describing a driving structure of the first working example of the liquid crystal display device according to the invention. 13 is a vertical scanning circuit, 14 a picture signal driving circuit, 15 a power supply circuit/controller, 17 a display section (liquid crystal panel), and 18 a common electrode driving circuit.

Driving LSI is connected with the display section 17, the vertical scanning circuit 13 and the picture signal driving circuit 14 are connected therewith, and a scanning signal voltage, a picture signal voltage, a timing signal and the like are supplied from the power supply circuit/controller 15 to conduct image display.

Fig. 4 is a descriptive view of a rubbing angle and an angle of a deflection plate in the liquid crystal display device according to the invention. 6 is a direction of an electric field, 19 a rubbing direction, and 20 a transmission axis of the deflection plate.

In the same figure, the rubbing directions 19 of the oriented films formed on the upper and lower substrates (a substrate on which the color filter is formed and a substrate on which the electrodes are formed) are approximately parallel

to each other, and an angle f_{LC} with the direction 6 of the electric field to be applied is 75° .

Two deflection plates (for example, G1220DU, trade name of a product made by Nitto Denko K.K.) are mounted above and below the liquid crystal panel. The deflected light transmission axis of one deflection plate is approximately parallel to the rubbing direction 19, namely 75° , and the deflected light transmission axis of another deflection plate is approximately orthogonal (-15°) to the rubbing direction 19. Normally close characteristics were thereby obtained.

A liquid crystal containing a compound having three fluoro groups in its terminal as a main component and having a positive dielectric anisotropy $\Delta\epsilon$ is held between the substrates. SiN is used in the passivation film 4, and its film thickness is in the range of from 0.1 to 0.7 μm . That is, the present inventors have found that by reducing the film thickness of the passivation film, the flat region of the oriented film is increased as shown in Fig. 6 to reduce the AC residual image of the oriented film.

Fig. 6(a) is a sectional view of an overlapped portion of the pixel electrode 3 and the passivation film 4 when the film thickness of the passivation film 4 is great enough. Fig. 6(b) is a sectional view of an overlapped portion of the pixel electrode 3 and the passivation film 4 when the film thickness of the passivation film 4 is in the range of from 0.1 to 0.7 μm .

Since the film thickness of the passivation film 4 is small in Fig. 6(b), the oriented film 5 is, as shown, flattened by X as compared with Fig. 6(a).

An orientation controlling force of the oriented film 5 is generated by so-called rubbing treatment. The flattening results in increasing the rubbed region and improving the orientation controlling force of the oriented film 5.

Accordingly, by improving the orientation controlling force of the oriented film 5, the AC residual image can be suppressed to conduct high-quality image display without display unevenness.

Moreover, with the same intensity of the electric field applied to the liquid crystal layer of a portion that contributes most to ON/OFF action of the display, the small film thickness of the oriented film 5 can decrease the intensity of the electric field applied to the interface of the oriented film. That is, by decreasing the intensity of the electric field applied to the interface of the oriented film, the AC residual image is suppressed.

Incidentally, it is advisable that the film thickness of the passivation film 4 is less than 0.5 μm . However, when the film is too thin, it cannot protect the pixel electrode 3 and the like. When it is thick, the AC residual image is not reduced. Thus, it has to be in the range of from 0.1 to 0.7 μm . Specifically, when the film thickness of the

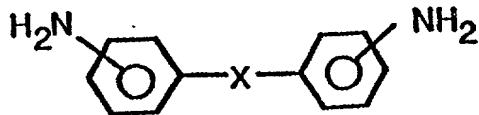
passivation film 4 and the residual extent (difference in brightness) of the AC residual image were comparatively examined, the AC residual image was less than 8 % in case of the film thickness of 0.7 μm , and the good image display was obtained.

Plasma CVD was used in the formation of this passivation film 4. This film formation took approximately 25 minutes.

A polyimide oriented film made of 2,2-bis[4-(p-aminophenoxy)phenylpropane] and pyromellitic acid dihydrate is used as the oriented film 5. Its film thickness is 50 nm.

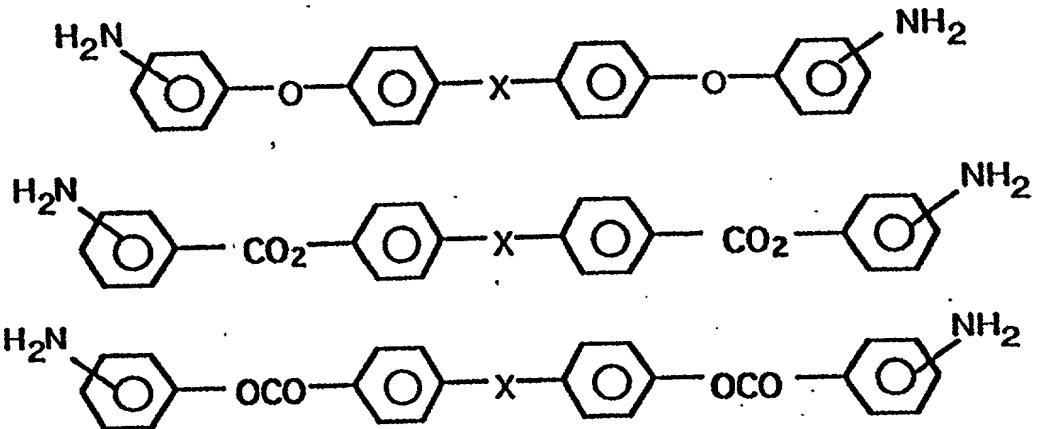
With respect to the other material of the oriented film, as an amine to be copolymerized with tetracarboxylic acid dihydrate, represented by the following [formula 1], phenylenediamine, diphenylenediamine, triphenylenediamine, compounds represented by

[formula 1]



(wherein X represents a direct bond, -O-, -CH₂-, -SO₂-, -CO-, -CO₂- or -CONH-), or compounds having structures represented by the following general [formulas 2]

[formulas 2]



(wherein X is a direct bond),

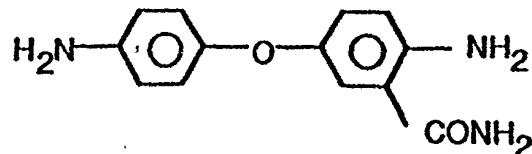
such as a bis(aminophenoxy)diphenyl compound and the like are used.

Specific examples include p-phenylenediamine, m-phenylenediamine, 4,4'-diaminoterphenyl, 4,4'-diaminodiphenylsulfone, 3,3'-diaminodiphenylsulfone, 4,4'-diaminodiphenyl benzoate, 4,4'-diaminodiphenylmethane, 2,2'-(4,4'-diaminodiphenyl)propane, 4,4'-bis(p-aminophenoxy)diphenylsulfone, 4,4'-bis(m-aminophenoxy)diphenylsulfone, 4,4'-bis(p-aminophenoxy)diphenyl ether, 4,4'-bis(p-aminophenoxy)diphenylketone, 4,4'-bis(p-aminophenoxy)diphenylmethane and 2,2'-(4,4'-bis(p-aminophenoxy)diphenyl)propane.

Still further, there are

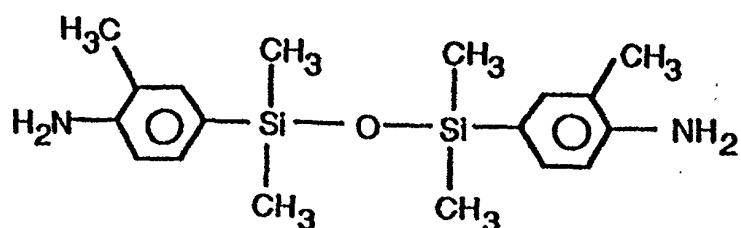
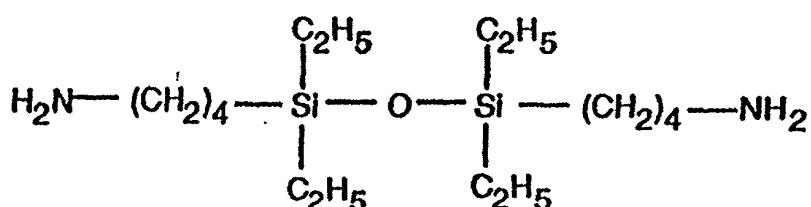
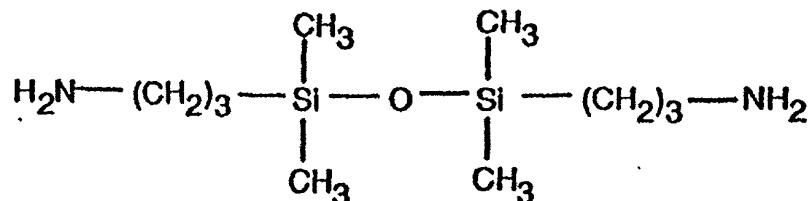
4,4'-diamino-3-carbamoyldiphenyl ether represented by the following [formula 3]

[formula 3]



and diaminosiloxane compounds of the following [formulas 4].

[formulas 4]



Furthermore, examples of a halogen group-free diamine copolymerizable with the foregoing include 4,4'-diaminodiphenyl ether-3-carbonamide, 3-3'-diaminodiphenylsulfone,

3-3'-dimethyl-4-4'diaminodiphenyl ether, 1,6-diaminohexane,
2-2'-bis[4-(4-aminophenoxy)diphenyl]propane,
2-2'-bis[4-(4-aminophenoxy)phenyl]methane,
2-2'-bis[4-(4-aminophenoxy)phenyl]sulfone,
2-2'-bis[4-(4-aminophenoxy)phenyl]ketone,
2-2'-bis[4-(4-aminophenoxy)phenyl]biphenyl,
2-2'-bis[4-(4-aminophenoxy)phenyl]cyclohexane,
2-2'-bis[4-(4-aminophenoxy)phenyl]methylcyclohexane,
bis[4-(4-aminobenzoyloxy)benzoic acid]propane,
bis[4-(4-aminobenzoyloxy)benzoic acid]cyclohexane,
bis[4-(4-aminobenzoyloxy)benzoic acid]methylcyclohexane,
bis[4-(4-aminomethylbenzoyloxy)benzoic acid]propane,
bis(4-aminobenzoyloxy)propane,
bis(4-aminobenzoyloxy)methane,
bis[2-(4-aminophenoxy)phenyl]methane,
bis[2-(4-aminophenoxy)-3,5-dimethylphenyl]methane,
bis[2-(4-aminophenoxy)-3,4,5-trimethylphenyl]methane,
bis[2-(4-aminophenoxy)-3,5,6-trimethylphenyl]methane,
bis[2-(4-aminophenoxy)-3,5-diethylphenyl]methane,
bis[2-(4-aminophenoxy)-5-n-propylphenyl]methane,
bis[2-(4-aminophenoxy)-5-isopropylphenyl]methane,
bis[2-(4-aminophenoxy)-5-methyl-3-isopropylphenyl]methane,
bis[2-(4-aminophenoxy)-5-n-butylphenyl]methane,
bis[2-(4-aminophenoxy)-5-isobutylphenyl]methane,
bis[2-(4-aminophenoxy)-3-methyl-5-t-butylphenyl]methane,

bis[2-(4-aminophenoxy)-5-cyclohexylphenyl]methane,
bis[2-(4-aminophenoxy)-3-methyl-5-cyclohexylphenyl]methane,
bis[2-(4-aminophenoxy)-5-methyl-3-cyclohexylphenyl]methane,
bis[2-(4-aminophenoxy)-5-phenylphenyl]methane,
bis[2-(4-aminophenoxy)-3-methyl-5-phenylphenyl]methane,
1,1-bis[2-(4-aminophenoxy)-5-methylphenyl]methane,
1,1-bis[2-(4-aminophenoxy)-5-dimethylphenyl]ethane,
1,1-bis[2-(4-aminophenoxy)-5-methylphenyl]propane,
1,1-bis[2-(4-aminophenoxy)-3,5-dimethylphenyl]propane,
2,2-bis[2-(4-aminophenoxy)phenyl]propane,
2,2-bis[2-(4-aminophenoxy)-3,5-dimethylphenyl]propane,
1,1-bis[2-(4-aminophenoxy)-5-methylphenyl]butane,
2,2-bis[2-(4-aminophenoxy)-3,5-dimethylphenyl]butane,
1,1-bis[2-(4-aminophenoxy)-5-methylphenyl]-3-methylpropane,
1,1-bis[2-(4-aminophenoxy)-3,5-dimethylphenyl]cyclohexane,
1,1-bis[2-(4-aminophenoxy)-5-methylphenyl]-3-3-5-trimethyl
cyclohexane and the like, and further diaminosiloxanes.
However, it is not limited to these.

Meanwhile, examples of the compound having the long-chain alkylene group as the acid component and other copolymerizable compounds can include octylsuccinic acid dianhydride, dodecylsuccinic acid dianhydride, octylmalonic acid dianhydride, decamethylenebistrimellitic acid dianhydride, decamethylenebistrimellitate dianhydride, 2,2-bis[4-(3,4-dicarboxyphenoxy)phenyl]octyltetracarboxyli

c acid dianhydride,
2,2-bis[4-(3,4-dicarboxybenzoyloxy)phenyl]tridecanetetracarboxylic acid dianhydride,
2,2-bis[4-(3,4-dicarboxyphenoxy)phenyl]tridecanetetracarboxylic acid dianhydride, stearic acid, stearyl chloride, pyromellitic acid dianhydride, methylpyromellitic acid dianhydride, 3,3',4,4'-biphenyltetracarboxylic acid dianhydride, dimethylenetrimellitic acid anhydride, 3,3',4,4'-biscyclohexanetetracarboxylic acid dianhydride, 3,3',4,4'-benzophenonetetracarboxylic acid dianhydride, 3,3',4,4'-diphenylmethanetetracarboxylic acid dianhydride, 3,3',4,4'-diphenyl ether tetracarboxylic acid dianhydride, 3,3',4,4'-diphenylsulfonetetracarboxylic acid dianhydride, 2,3,6,7-naphthalenetetracarboxylic acid dianhydride, 3,3',4,4'-diphenylpropanetetracarboxylic acid dianhydride, 2,2-bis[4-(3,4-dicarboxyphenoxy)phenyl]propanetetracarboxylic acid dianhydride, 2,2-bis[4-(3,4-dicarboxyphenoxy)phenyl]hexafluoropropanetetracarboxylic acid dianhydride, 2,2-bis[4-(3,4-dicarboxybenzoyloxy)phenyl]propanetetracarboxylic acid dianhydride, cyclopantanetetracarboxylic acid dianhydride, 1,2,3,4-cyclobutanetetracarboxylic acid dianhydride, bicyclo(2,2,2)octa-7-en-2,3,5,6-tetracarboxylic acid dianhydride, 1,2,3,4-cyclopantanetetracarboxylic acid

dianhydride, 1,2,3,4-butanetetracarboxylic acid dianhydride and the like.

Moreover, the formation of the oriented film can easily be conducted by not only a printing method but also a wet method such as a spin coating method, a bar coating method or the like. However, when it is formed, like an ordinary oriented film, by the printing method, patterning or the like after the film formation is dispensed with, and a productivity in particular can be improved.

The presence or absence of the residual image formed by pure AC driving of the thus-formed liquid crystal display device can directly be judged by measuring whether or not the change in B-V characteristics (brightness-voltage characteristics) in the pure AC driving (change in initial brightness B and brightness B after retention for 30 minutes with half tone when white display is conducted and retained for 30 minutes to give the maximum brightness display in the usual driving and brightness-voltage characteristics are likewise measured) occurs. That is, when the B-V characteristics are changed, the B-V characteristics after display are different in two zones in which different displays are conducted respectively, and there is a difference in the B-V characteristics even when the same voltage is inputted, with the result that the difference in brightness occurs in the two zones and this is observed as a residual image.

Fig. 5 is a block diagram of a measurement system for evaluating change in B-V characteristics. 21 is a thermostat, 22 a monitoring window (glass window), 23 a digital multimeter, 24 a measurement controller, 25 a sample (liquid crystal display device), 26 a back light, 27 a common voltage power supply, 28 a signal voltage supply, and 29 a gate voltage power supply.

The liquid crystal display device 25 as the sample is measured after the temperature is stabilized for 4 or more hours along with the back light 26. The liquid crystal panel 25 is subjected to pure AC driving (AC driving) with a DC component being 0 at a common voltage of 0 V.

A gate of the liquid crystal display device 25 is subjected to DC driving, and 16 V is inputted into the gate. The common voltage was a fixed value of 0 V. An output from a brightness system is inputted into the measurement controller 24 by the digital multimeter as a brightness value.

And, the change of a B-V curve before and after the AC driving is measured in the following order (1) to (3).

(1) Brightness B_b (V_{sig}) is successively measured while a signal voltage V_{sig} is increased from 0 V.

(2) Driving is conducted for 30 minutes at a signal voltage V_{max} at which brightness reaches a maximum.

(3) Brightness B_a (V_{sig}) is successively measured while a signal voltage V_{sig} is decreased from V_{max} to 0 V.

Consequently, a brightness change value ΔB (V_{sig}) before

and after the pure AC driving

$$\Delta B(V_{sig})(\%) = [B_a(V_{sig}) - B_b(V_{sig})]/B_b(V_{sig}) \quad \dots (1)$$

can be obtained.

Incidentally, the measurement was conducted at 55°C. As a result, $\Delta B(V_{sig})$ was less than 8 %, and the good display characteristics were obtained.

When a coating property of the substrate is improved by a method such as UV/ozone irradiation or the like in the formation of the oriented film, the oriented film is easily formed more uniformly throughout the surface to further improve coverage of electrodes. Further, when the passivation film is thin to a certain extent, crack becomes large, and the coating property in the crack is easily improved by a method such as UV/ozone irradiation or the like to further improve coverage by the oriented film.

Next, second to tenth working examples of the invention are described by referring to Table 1.

(Examples 2 to 10)

Liquid crystal display devices were produced in the same manner as in Example 1 except for the following items, and were evaluated. That is, the film thickness of the oriented film is 0.3 μm , and the time required for formation of the passivation film is approximately 15 minutes.

Even when the thus-produced liquid crystal display devices were subjected to half tone display at 55°C for 500

hours, no display defect occurred.

With respect to the liquid crystal display devices, the AC residual image was measured, and the results were as shown in [Table 1].

Table 1

	Diamine component	Acid component	Weight average molecular weight*	AC residual image**
Example 2	2,2'-bis[4-(4-aminophenoxy)phenyl]biphenyl	octylsuccinic acid dianhydride	12000	<8%
Example 3	bis[2-(4-aminophenoxy)-5-methylphenyl]methane	2,2-bis[4-(3,4-dicarboxy-phenoxy)phenyl]octyltetra-carboxylic acid dianhydride	7290	<8%
Example 4	1,1-bis[2-(4-aminophenoxy)-3,5-dimethylphenyl]ethane	3,3',4,4'-biscyclohexane-tetracarboxylic acid dianhydride	3930	<8%
Example 5	2,2-bis[2-(4-aminophenoxy)phenyl]propane	2,3,6,7-naphthalenetetra-carboxylic acid dianhydride	18530	<8%
Example 6	1,1-bis[2-(4-aminophenoxy)-5-methylphenyl]butane	2,2-bis[4-(3,4-dicarboxy-phenoxy)phenyl]propane-tetracarboxylic acid dianhydride	19000	<8%
Example 7	1,1-bis[2-(4-aminophenoxy)-3,5-dimethylphenyl]clohexane	2,2-bis[4-(3,4-dicarboxy-benzoxyloxy)phenyl]propane-tetracarboxylic acid dianhydride	27000	<8%
Example 8	1,1-bis[2-(4-aminophenoxy)-5-methylphenyl]clohexane	cyclopentanetetracarboxylic acid dianhydride	8510	<8%
Example 9	bis[4-(4-aminobenzoyl-oxy)benzoic acid]propyl ester	1,2,3,4-cyclobutanetetra-carboxylic acid dianhydride	24180	<8%
Example 10	bis[2-(4-aminophenoxy)-5-n-propylphenyl]methane	1,2,3,4-cyclopentanetetra-carboxylic acid dianhydride	22390	<8%
Comparative Example 1	m-phenylenediamine	1,5bis[4-(3,4-dicarboxybenzoyloxy)phenyl]-decafluoropentanetetracarboxylic acid dianhydride + 1,2,3,4-butanetetra-carboxylic acid dianhydride	4000	12%

* Weight average molecular weight calculated as standard polystyrene

** Defined by formula (1) in the description of the specification

Further, [H] pattern was displayed for 30 minutes, and then subjected to black display. At this time, the residual image was visually observed at 0 to 40°C and 55°C. The results are shown in [Table 2].

Table 2

	AC residual image	Use temperature 0 to 40°C	Use temperature 55°C
Examples 1 to 10	<8%	OO	OO
Comparative Example 2	8 to 12%	O	Δ
Comparative Example 1	>12%	x	x

Visual observation

OO : No residual image is seen.

O : A residual image disappears within 3 minutes.

Δ : A residual image disappears within 10 minutes.

x : A residual image is seen after 10 minutes.

From [Table 1] and [Table 2], it is found that when the AC residual image is 8 to 12 %, the residual image disappears relatively quickly in the use temperature range, while when the AC residual image is less than 8 %, the residual image does not occur either at the high temperature or in the use temperature

range and the good display quality is maintained.

For comparing the effects in the above-mentioned Examples of the invention, Comparative Examples are described.

(Comparative Example 1)

A liquid crystal display device was produced in the same manner as in (Example 1) except for the following matters, and was evaluated.

That is, 1.0 mol% of m-phenylenediamine was dissolved in N-methyl-2-pyrrolidone. To this was added 0.1 mol of 1,5bis[4-(3,4-dicarboxybenzoyloxy)phenyl]decafluoro-pentan etetracarboxylic acid dianhydride, and the reaction was conducted at 40°C for 2 hours to form an oligomer containing a fluoro group of a side chain type and having a weight average molecular weight of approximately 4,000 calculated as standard polystyrene. Further, 0.9 mol of 1,2,3,4-butanetetracarboxylic acid dianhydride was added, and the reaction was conducted at 20°C for 8 hours and at 130°C for 1 hour to obtain a polyoligomer amic acid imide varnish in which a ratio of a fluoro group-containing oligomer was approximately 10 %. This varnish was diluted to a concentration of 6 %, and γ -aminopropyltriethoxysilane was added in an amount of 0.3 % by weight as a solid content. Thereafter, printing formation was conducted, and heat treatment was conducted at 200°C for 30 minutes to form an oriented film of approximately 70 nm.

The thus-formed display device was measured in the same

manner as mentioned above. Consequently, the AC residual image is more than 12 %, and the residual image remains.

(Comparative Example 2)

A liquid crystal display device was produced in the same manner as in (Example 1) except for the following matters.

That is,

3,4-dicarboxy-1,2,3,4-tetrahydro-1-naphthalenesuccinic acid dianhydride, p-phenylenediamine and 1-hexadecanoxy2,4-diaminobenzene were reacted in N-methyl-2-pyrrolidone at room temperature for 10 hours to form a polyamic acid intermediate solution.

To this polyamic acid intermediate solution were added acetic acid anhydride and pyridine as an imidation catalyst, and the reaction was conducted at 50°C for 3 hours to form a polyimide resin. This varnish was diluted to a concentration of 6 %, and printing formation was conducted. Heat treatment was conducted at 200°C for 30 minutes to form an oriented film of approximately 70 nm.

This was evaluated. Consequently, the AC residual image was 10 %. The residual image slightly remained in the use temperature range. The residual image remained at the high temperature of 55°C.

[Industrial Applicability]

As described above, according to the invention, the use of the polyimide oriented film free from the side chain-type

structure can suppress the AC residual image in the liquid crystal display device comprising a pair of substrates and a liquid crystal layer held between the pair of substrates, at least one of the pair of substrates being provided with plural electrodes for applying an electric field approximately parallel to the surface of the substrate to the liquid crystal layer, a protecting film formed for protecting at least one of the plural electrodes and oriented films formed on the protecting film or the electrodes and can provide the high-quality image display without display unevenness.

CLAIMS

1. A liquid crystal display device comprising a pair of substrates and a liquid crystal layer held between the pair of substrates,

at least one of the pair of substrates being provided with plural electrodes for applying an electric field to the liquid crystal layer, a protecting film for protecting at least one of the plural electrodes and oriented films formed to cover the protecting film or the electrodes, characterized in that the film thickness of the protecting film is in the range of from 0.1 μm to 0.7 μm , and

an AC residual image of the oriented films is less than 8 %.

2. The liquid crystal display device according to claim 1, characterized in that a specific resistance of the liquid crystal layer is $10^{10} \Omega\cdot\text{cm}$ or more.

3. The liquid crystal display device according to claim 1 or 2, characterized in that at least one of the oriented films is an organic polymer containing at least one of a polymer and an oligomer in which a weight substance with a long-chain alkyl group applied to an amine component or an acid sentence is at least 5 % and at most 30 % of the total molar amount.

4. The liquid crystal display device according to claim 3, characterized in that a weight average molecular weight

of the polymer and the oligomer is at least 2,000 and at most 30,000.

5. The liquid crystal display device according to claim 3 or 4, characterized in that the polymer and the oligomer contain a long-chain alkylene group of at least one of a main chain type and a terminal type.

6. The liquid crystal display device according to any of claims 1 to 5, characterized in that the oriented film is an organic polymer of a polymer and/or oligomer amic acid imide type, a polymer and/or oligomer amide-imide type, a polymer and/or oligomer imidosiloxane type or a polymer and/or oligomer amide-imide type containing a long-chain alkylene group.

7. A liquid crystal display device comprising a pair of substrates and a liquid crystal layer held between the pair of substrates,

at least one of the pair of substrates being provided with at least a pair of electrodes for applying an electric field to the liquid crystal layer,

protecting films for protecting the plural electrodes and

oriented films formed on the protecting films and the electrodes, characterized in that

the film thickness of the protecting films is less than 0.5 μm , and

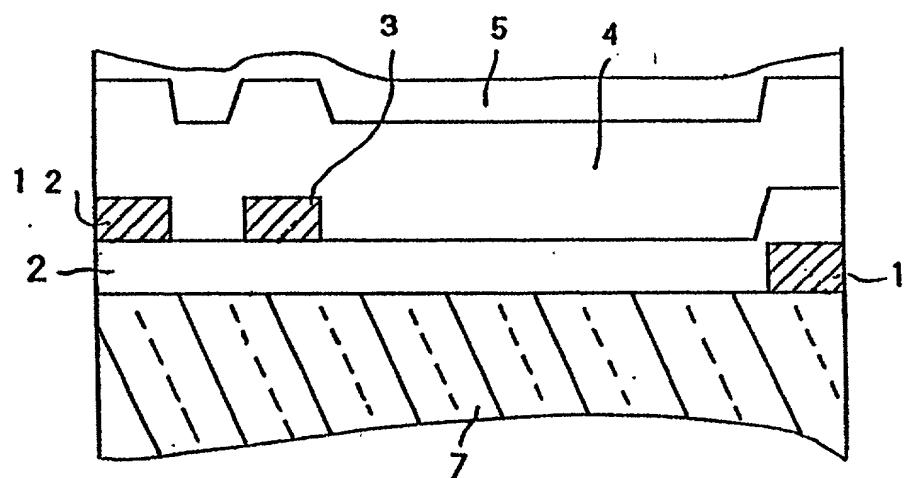
an AC residual image of the oriented films is less than

8 %.

ABSTRACT

A pair of substrates and a liquid crystal layer held between the pair of substrates are provided, at least one of the pair of substrates has plural electrodes for applying an electric field approximately parallel to the substrate to the liquid crystal layer, a protecting film for protecting at least one of the plural electrodes and oriented films to cover the protecting film or the electrodes, and an AC residual image of the oriented film is less than 8 % to thereby enable high-quality image display upon eliminating display defect caused by the AC residual image.

FIG.1



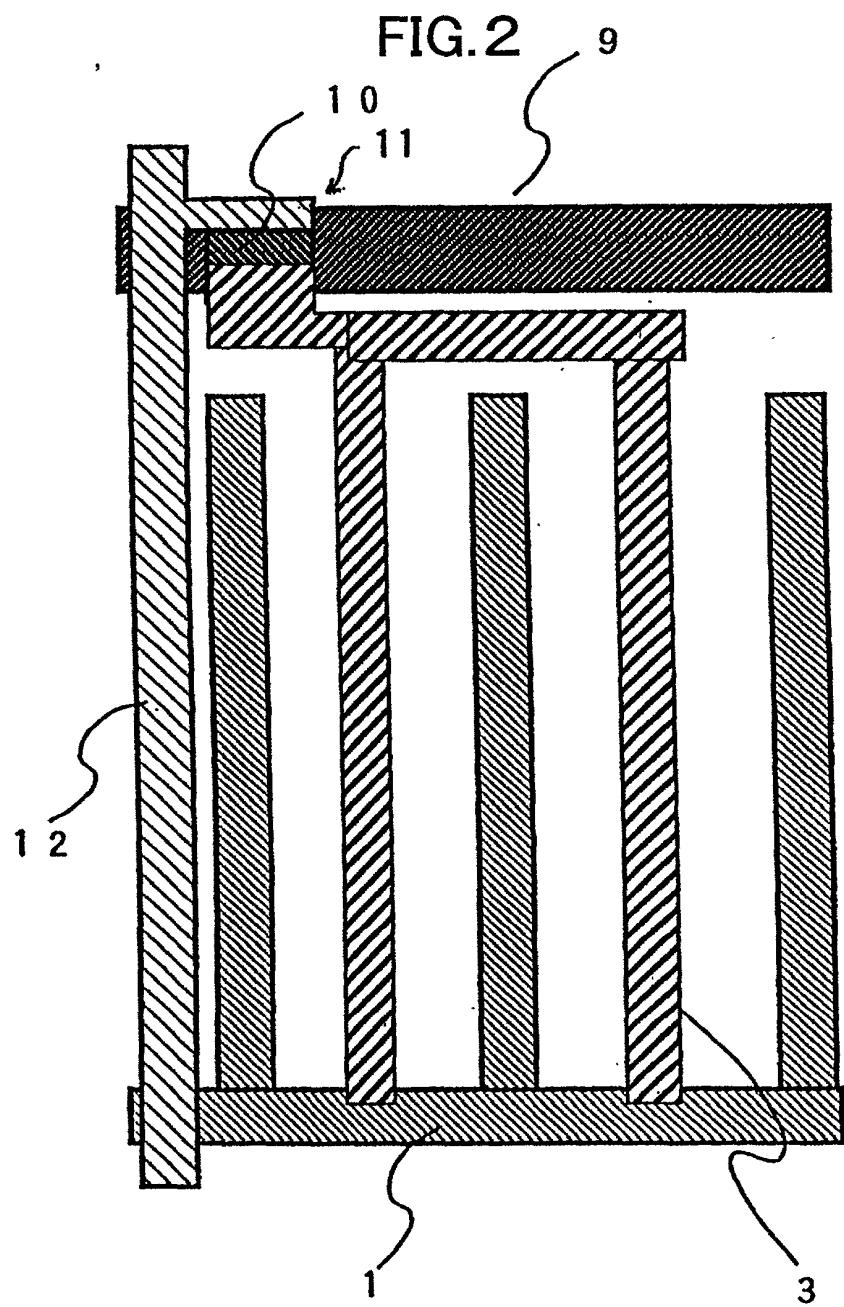


FIG.3

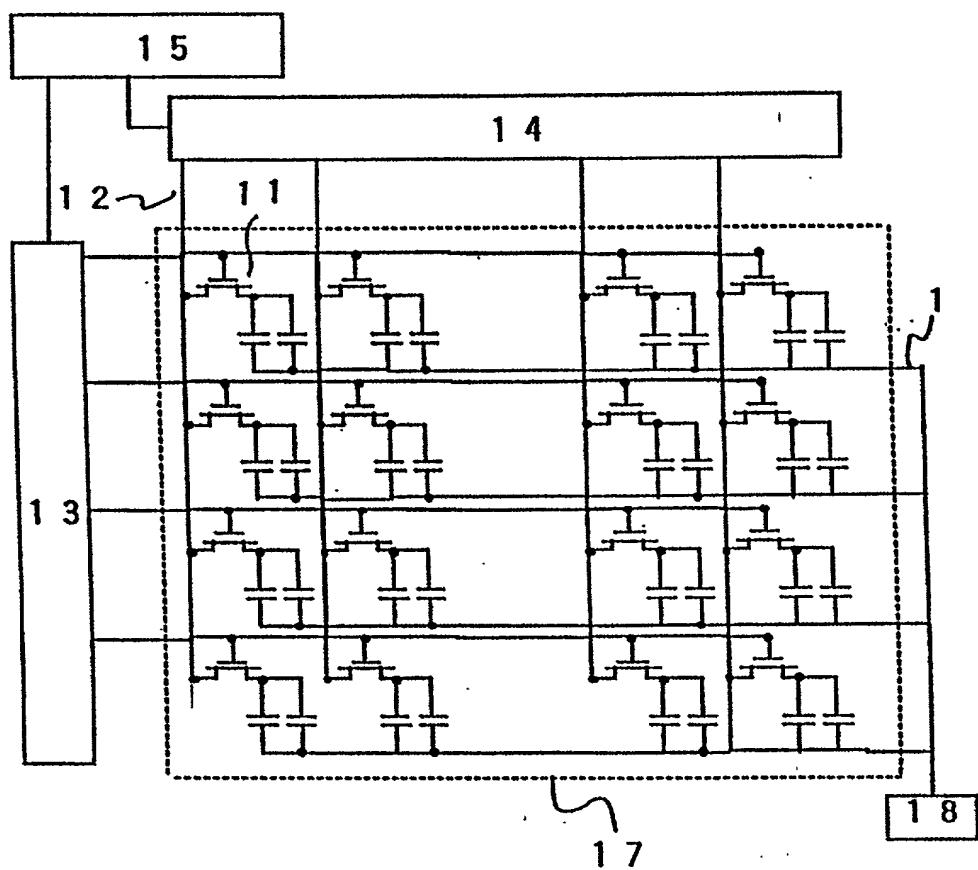


FIG.4

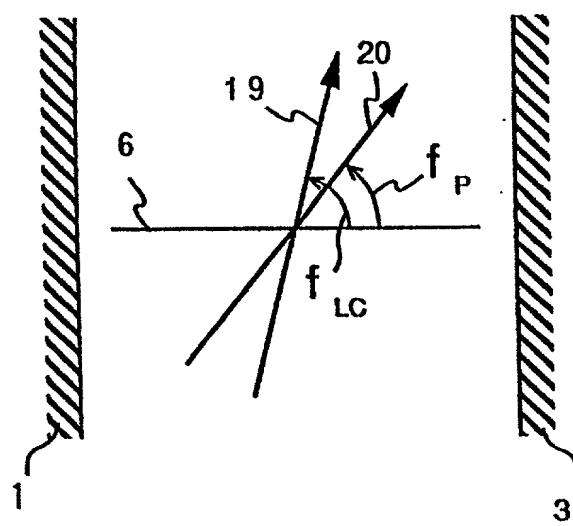


FIG.5

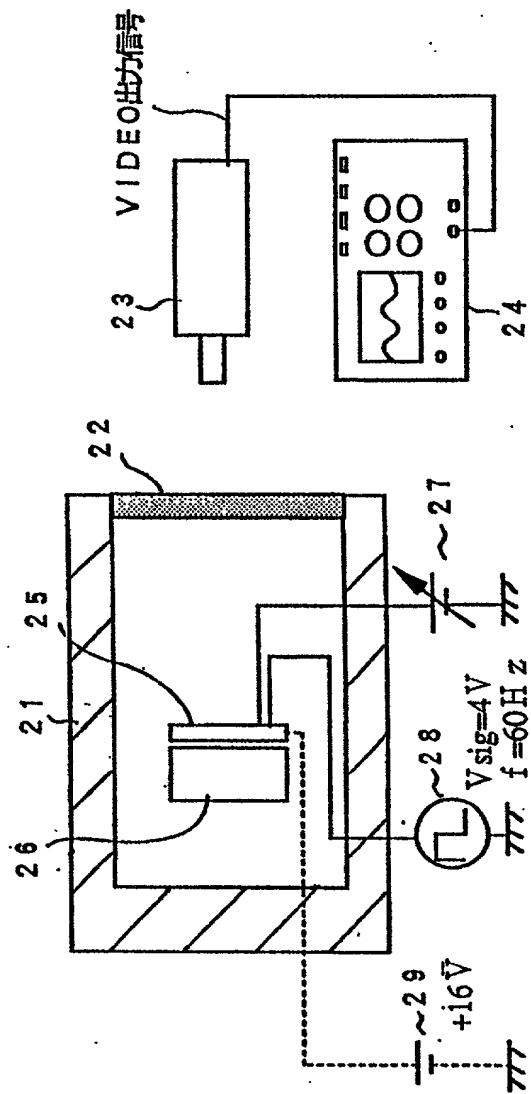
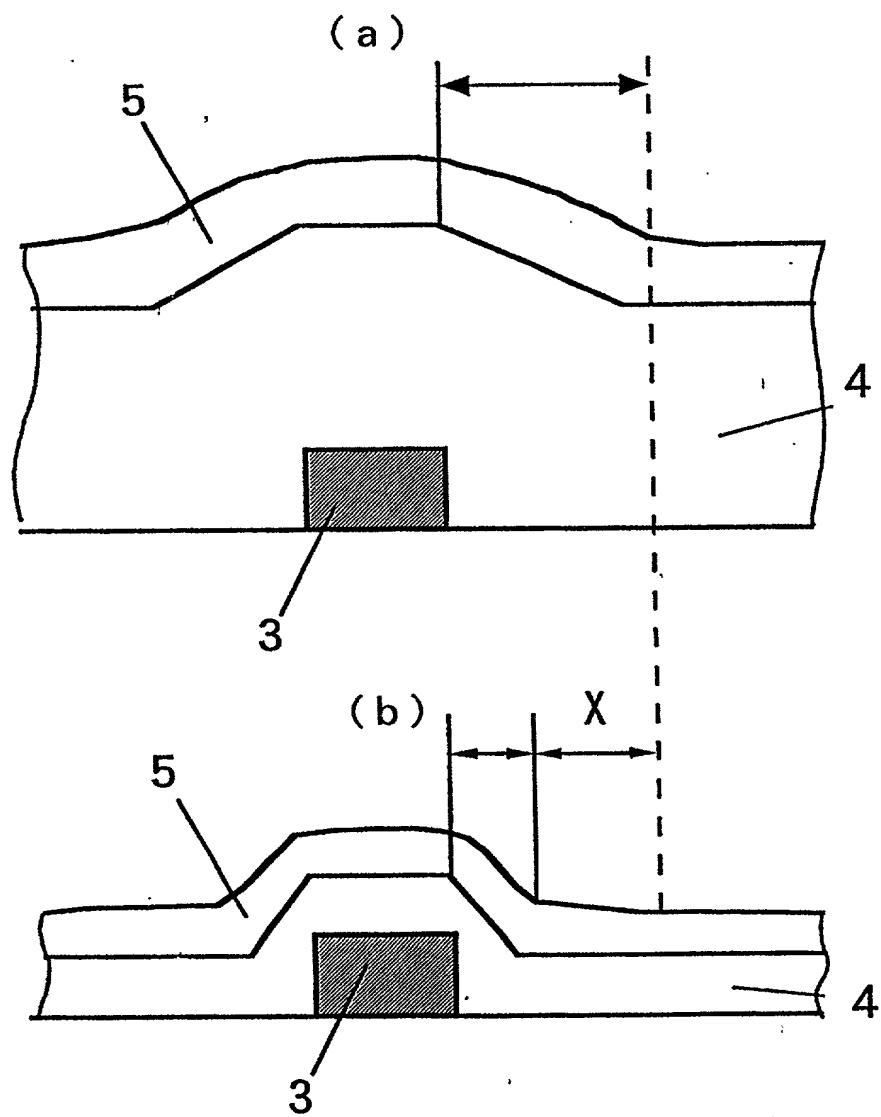


FIG. 6



Declaration and Power of Attorney For Patent Application

特許出願宣言書及び委任状

Japanese Language Declaration

日本語宣言書

下記の氏名の発明者として、私は以下の通り宣言します。

As a below named inventor, I hereby declare that:

私の住所、私書箱、国籍は下記の私の氏名の後に記載された通りです。

My residence, post office address and citizenship are as stated next to my name.

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I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

LIQUID CRYSTAL DISPLAY DEVICE

上記発明の明細書（下記の横で×印がついていない場合は、本書に添付）は、

The specification of which is attached hereto unless the following box is checked:

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was filed on
as United States Application Number or
PCT International Application Number
and was amended on
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Prior Foreign Application(s)
外国での先行出願

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Priority Not Claimed
優先権主張なし

22 / January / 1999	<input type="checkbox"/>
(Day/Month/Year Filed) (出願年月日)	<input type="checkbox"/>
(Day/Month/Year Filed) (出願年月日)	<input type="checkbox"/>

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(Application No.) (出願番号)	(Filing Date) (出願日)	(Application No.) (出願番号)	(Filing Date) (出願日)
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(Status: Patented, Pending, Abandoned) (現況: 特許許可済、係属中、放棄済)
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POWER OF ATTORNEY: As a named Inventor, I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith (list name and registration number)

10

Donald R. Antonelli, Reg. No. 20,298; David T. Terry, Reg. No. 20,178; Melvin Kraus, Reg. No. 22,466; William I. Solomon, Reg. No. 28,565; Gregory E. Montone, Reg. No. 28,141; Ronald J. Shore, Reg. No. 28,577; Donald E. Stout, Reg. No. 26,422; Alan E. Schiavelli, Reg. No. 32,087; James N. Dresser, Reg. No. 22,973 and Carl I. Brundidge, Reg. No. 29,621

書類送付先

Send Correspondence to:

Antonelli, Terry, Stout & Kraus, LLPSuite 18001300 North Seventeenth StreetArlington, Virginia 22209

直接電話連絡先：(氏名及び電話番号)

Direct Telephone Calls to: (name and telephone number)

Telephone: (703) 312-6600

Fax: (703) 312-6666

唯一または第一発明者

Full name of sole or first Inventor

Setsuo Kobayashi

1-60

発明者の署名

日付

Inventor's signature

Setsuo Kobayashi

Date

July 17, 2001

住所

Residence

Mobera, Japan

JPX

国籍

Citizenship

Japan

私書箱

Post Office Address

c/o Hitachi, Ltd., Electron Tube and Devices Division
3300, Hayano Mobera-shi, Chiba-ken, 297-8622 Japan

(第二以降の共同発明者についても同様に記載し、署名をすること)

(Supply similar information and signature for second and subsequent joint inventors.)

第二共同発明者		Full name of second joint inventor, if any Kazuhiko Yanagawa 200	
第二共同発明者の署名	日付	Second Inventor's signature Kazuhiko Yanagawa	Date July 18, 2001
住所		Residence Mobara, Japan JPX	
国籍		Citizenship Japan	
私書箱		Post Office Address c/o Hitachi, Ltd., Electron Tube and Devices Division 3300, Hayano Mobara-shi, Chiba-ken, 297-8622 Japan	
第三共同発明者		Full name of third joint inventor, if any	
第三共同発明者の署名	日付	Third inventor's signature	Date
住所		Residence	
国籍		Citizenship	
私書箱		Post Office Address	
第四共同発明者		Full name of fourth joint inventor, if any	
第四共同発明者の署名	日付	Fourth inventor's signature	Date
住所		Residence	
国籍		Citizenship	
私書箱		Post Office Address	
第五共同発明者		Full name of fifth joint inventor, if any	
第五共同発明者の署名	日付	Fifth inventor's signature	Date
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国籍		Citizenship	
私書箱		Post Office Address	

(第六以降の共同発明者についても同様に記載し、署名すること)
(Supply similar information and signature for sixth and subsequent joint inventors.)